## NSN 5962-01-116-7212

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View Online at https://aerobasegroup.com/nsn/5962-01-116-7212 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** 0.280 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+200.0 degrees celsius **End Application:** 5820-01-108-9658 20183 **Features Provided:** W/open collector and hermetically sealed and programmable and programmed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

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